

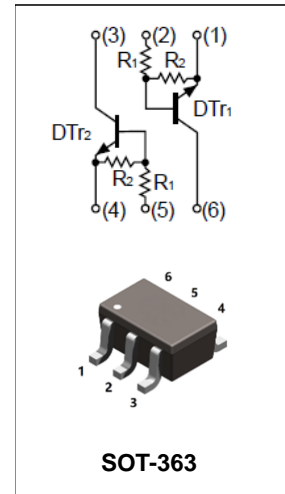


### Features

- Two DTC143Z transistors are built-in a package
- Built-in biasing resistors (R<sub>1</sub>: 4.7kΩ, R<sub>2</sub>: 47kΩ)
- Transistor elements are independent, eliminating interference
- Mounting cost and area can be cut in half

### Mechanical Data

- Case: SOT-363
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208



### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
UMH13N	SOT-363	3000 pcs / Tape & Reel	H13

### Maximum Ratings (@ T<sub>A</sub> = 25°C unless otherwise specified)

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	50	V
V <sub>CE0</sub>	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
V <sub>CC</sub>	Supply Voltage	50	V
V <sub>I</sub>	Input Voltage	-5 to +30	V
I <sub>O</sub>	Output Current	100	mA
I <sub>C(Max)</sub>	Collector Current	100	mA

### Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation *1	P <sub>D</sub>	300	mW
Thermal Resistance, Junction to Ambient Air	R <sub>θJA</sub>	417	°C /W
Operating Junction Temperature Range	T <sub>J</sub>	-55 ~ +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 ~ +150	°C

Note 1: Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint



## Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-base Cut-off Current	$I_{CBO}$	$V_{CB} = 50\text{V}, I_E = 0$	-	-	100	nA
Collector-emitter Cut-off Current	$I_{CEO}$	$V_{CE} = 30\text{V}, I_B = 0$	-	-	1	$\mu\text{A}$
Emitter-base Cut-off Current	$I_{EBO}$	$V_{EB} = 5\text{V}, I_C = 0$	-	-	170	$\mu\text{A}$
Input Voltage	$V_{I(OFF)}$	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$	0.5	-	-	V
Input Voltage	$V_{I(ON)}$	$V_O = 0.3\text{V}, I_O = 5\text{mA}$	-	-	1.3	V
DC Current Gain	$h_{FE}$	$I_C = 10\text{mA}, V_{CE} = 5\text{V}$	100	-	-	-
Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C/I_B = 5\text{mA}/0.25\text{mA}$	-	-	0.3	V
Input Resistor	$R_1$		3.29	4.7	6.11	k $\Omega$
Resistance ratio	$R_2/R_1$		8	10	12	-
Gain-Bandwidth Product	$f_T$	$V_{CE} = 10\text{V}, I_E = 5\text{mA}$ $f = 100\text{MHz}$	-	250	-	MHz



## Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

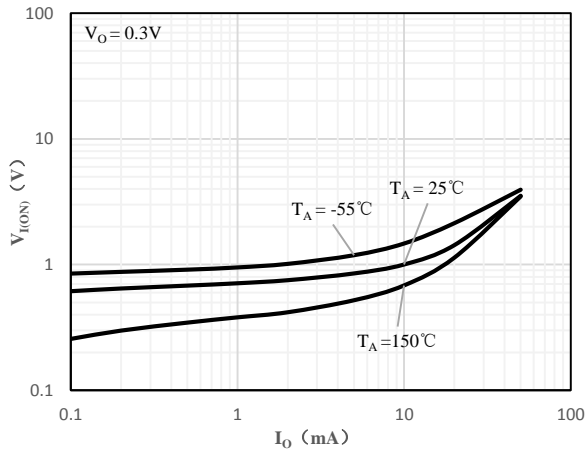


Fig 1 Input Voltage vs Output Current

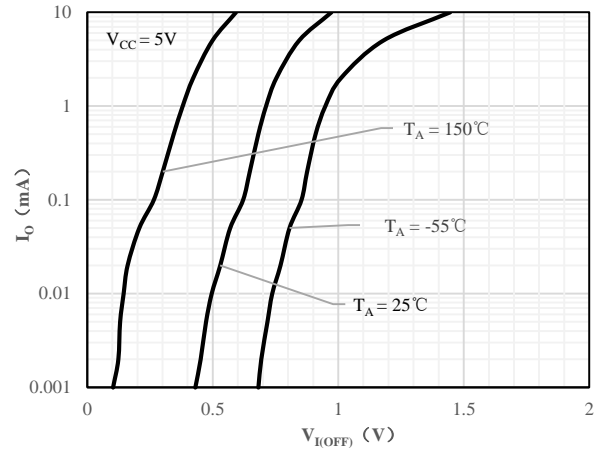


Fig 2 Output Current vs Input Voltage

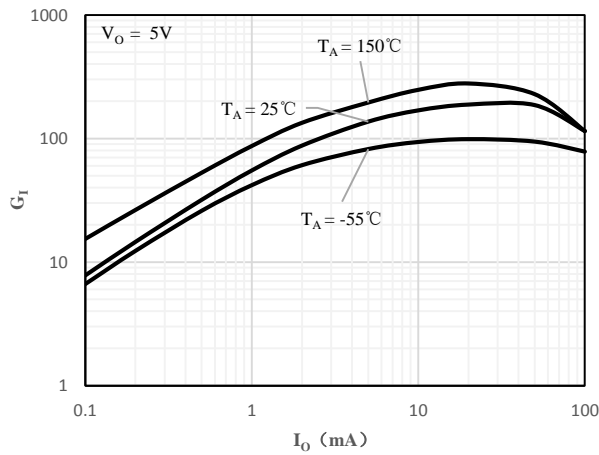


Fig 3 DC Current Gain vs Output Current

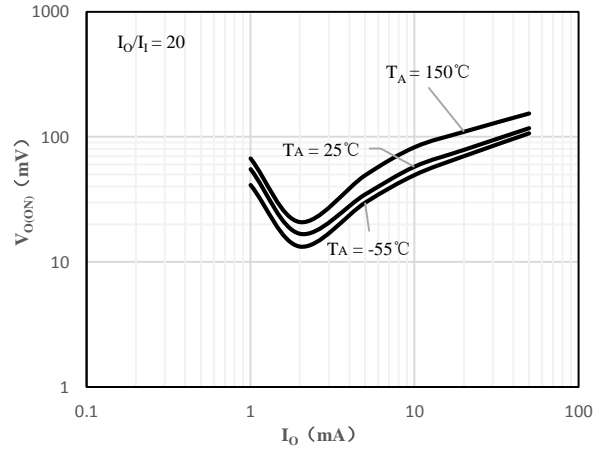
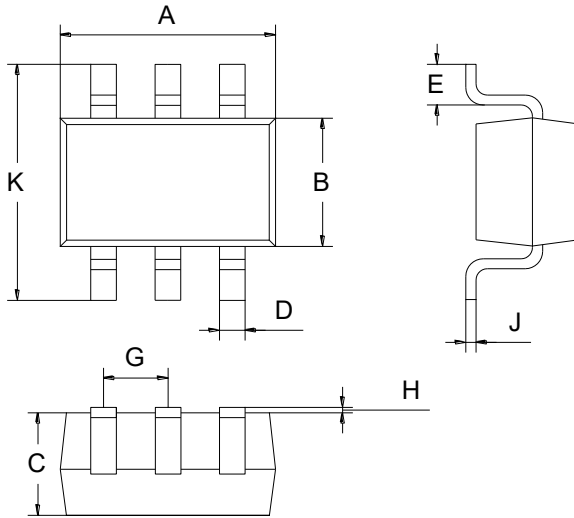


Fig 4 Output Voltage vs Output Current



## Package Outline Dimensions (Unit: mm)



SOT-363		
Dimension	Min.	Max.
A	2.00	2.20
B	1.15	1.35
C	0.85	1.05
D	0.15	0.35
E	0.25	0.40
G	0.60	0.70
H	0.02	0.10
J	0.05	0.15
K	2.20	2.40

## Mounting Pad Layout (Unit: mm)

### SOT-363

